

Solid State Relay OCMOS FET

PS7522-1A,-2A,PS7522L-1A,-2A

6, 8-PIN DIP, SLOW SWITCHING TYPE 1-ch, 2-ch Optical Coupled MOS FET

DESCRIPTION

The PS7522-1A, -2A and PS7522L-1A, -2A are solid state relays containing GaAs LEDs on the light emitting side (input side) and MOS FETs on the output side.

They are suitable for equipments which are necessary to prevent some noise, because of their slow switching speed at turn-on or turn-off.

The PS7522L-1A, -2A have a surface mount type lead.

★ FEATURES

- 1 channel type (1 a output) or 2 channel type (1 a + 1 a output)
- Low LED operating current (IF = 1 mA)
- · Designed for AC/DC switching line changer
- Small package (6, 8-pin DIP)
- Slow turn-on time, slow turn-off time (ton = 12 ms MAX., toff = 6.5 ms MAX.)
- · Low offset voltage
- PS7522L-1A, -2A: Surface mount type
- UL approved: File No. E72422 (S)
- BSI approved: No. 8245/8246
- CSA approved: No. CA 101391

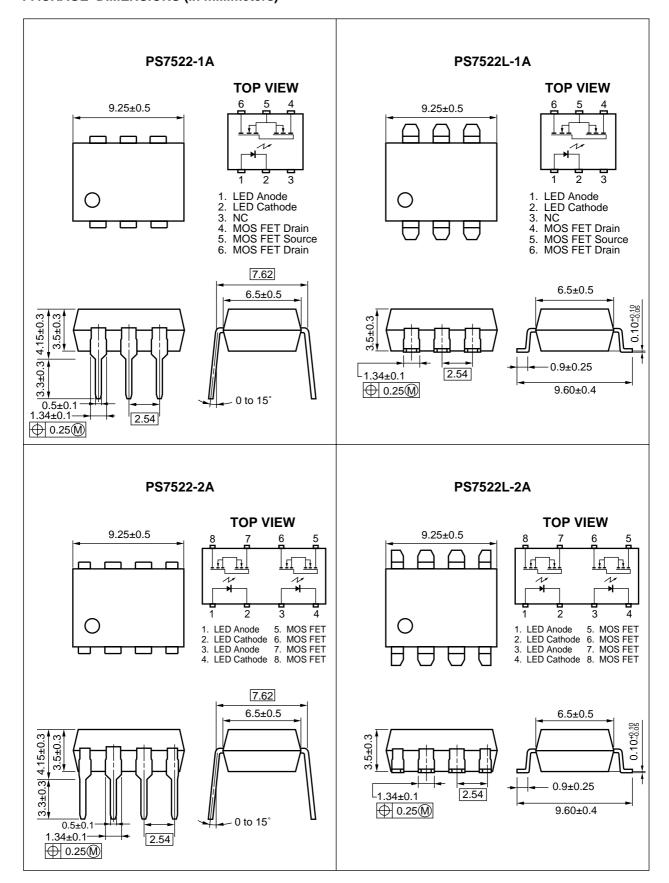
APPLICATIONS

- · Exchange equipment
- · Measurement equipment
- FA/OA equipment

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

PACKAGE DIMENSIONS (in millimeters)



★ ORDERING INFORMATION

Part Number	Package	Packing Style	Application Part Number*1
PS7522-1A	6-pin DIP	Magazine case 50 pcs	PS7522-1A
PS7522L-1A			PS7522L-1A
PS7522L-1A-E3		Embossed Tape 1 000 pcs/reel	
PS7522L-1A-E4			
PS7522-2A	8-pin DIP	Magazine case 50 pcs	PS7522-2A
PS7522L-2A			PS7522L-2A
PS7522L-2A-E3		Embossed Tape 1 000 pcs/reel	
PS7522L-2A-E4			

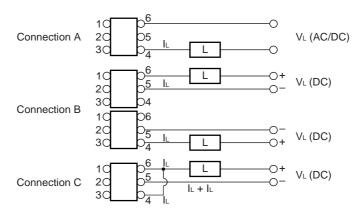
^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Parameter				Rati		
			Symbol	PS7522-1A, PS7522L-1A	PS7522-2A, PS7522L-2A	Unit
Diode	Forward Current (DC)		I F	50		mA
	Reverse Voltage		VR	5.0		V
	Power Dissipation		Po	50		mW/ch
Peak Forward Current ⁻¹			IFP	1		Α
MOS FET	Break Down Voltage		VL	200		V
	Continuous	Connection A	lı	200		mA
	Load Current ²	Connection B		350	-	
		Connection C		400	-	
	Pulse Load Current ⁻³ (AC/DC Connection)		Ігь	400		mA
	Power Dissipation		Po	560	375	mW/ch
Isolation Voltage ^{*4}			BV	1 500		Vr.m.s.
Total Power Dissipation			Рт	610	850	mW
Operating Ambient Temperature			TA	-40 to +80		°C
Storage Temperature			T _{stg}	-40 to +100		°C

^{*1} PW = 100 μ s, Duty Cycle = 1 %

^{*2} Conditions: IF \geq 2 mA. The following types of load connections are available.



^{*3} PW = 100 ms, 1 shot

^{*4} AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and output

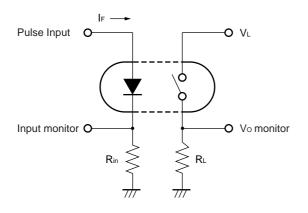
RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)

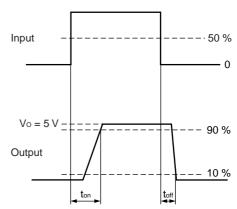
Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	lF	1	10	20	mA
LED Off Voltage	VF	0		0.5	V

★ ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

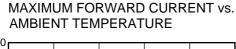
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 1.4 mA		1.1	1.4	V
	Reverse Current	lR	V _R = 5 V			5.0	μΑ
MOS FET	Off-state Leakage Current	Loff	V _D = 200 V		0.03	1.0	μΑ
	Output Capacitance	Cout	V _D = 0 V, f = 1 MHz		165		pF/ch
Coupled	LED On-state Current	IFon	IL = 200 mA			1.0	mA
	On-state Resistance	Ron1	IF = 1.4 mA, IL = 10 mA		3.0	5.0	Ω
		Ron2	I _F = 10 mA, I _L = 200 mA, t ≤ 20 ms				
	Turn-on Time ^{*1}	ton	I _F = 1.4 mA, V _O = 60 V, PW ≥ 50 ms		8.5	12	ms
	Rise Time	t r		0.80	2.78		
	Turn-off Time ^{*1}	toff			3.0	6.5	
	Fall Time	t f		0.4	0.8		
	Isolation Resistance	R _{I-O}	Vi-o = 1.0 kVpc	10°			Ω
	Isolation Capacitance	Сі-о	V = 0 V, f = 1 MHz		1.1		pF/ch

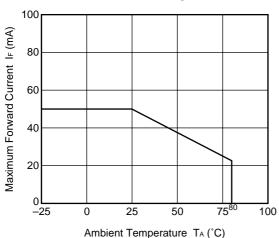
*1 Test Circuit for Switching Time



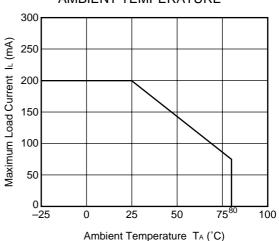


★ TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise specified)

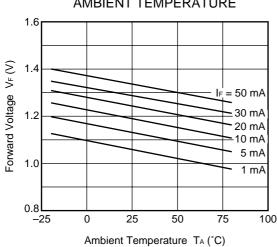




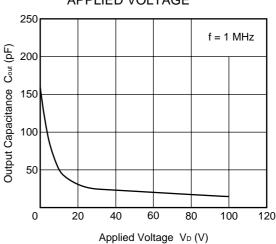
MAXIMUM LOAD CURRENT vs. AMBIENT TEMPERATURE



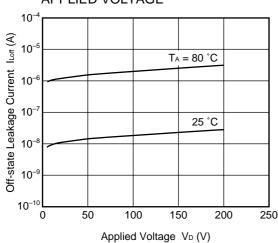
FORWARD VOLTAGE vs. AMBIENT TEMPERATURE



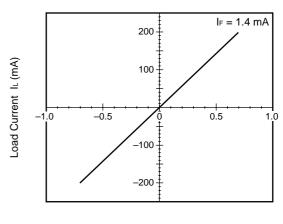
OUTPUT CAPACITANCE vs. APPLIED VOLTAGE



OFF-STATE LEAKAGE CURRENT vs. APPLIED VOLTAGE

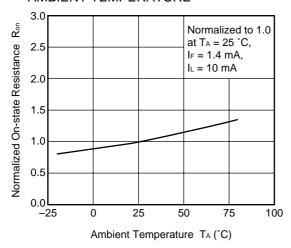


LOAD CURRENT vs. LOAD VOLTAGE

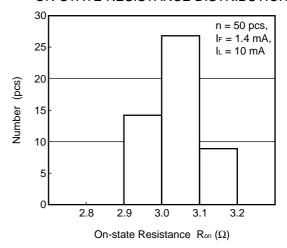


Load Voltage V_L (V)

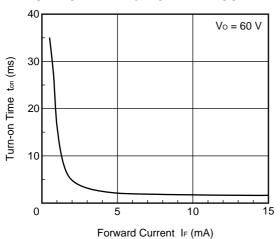
NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE



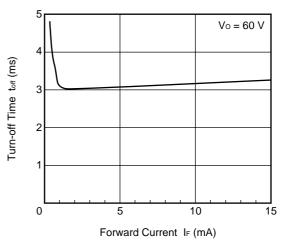
ON-STATE RESISTANCE DISTRIBUTION



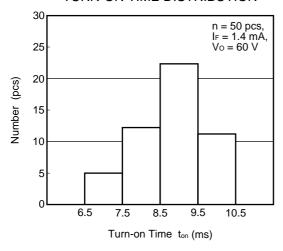
TURN-ON TIME vs. FORWARD CURRENT



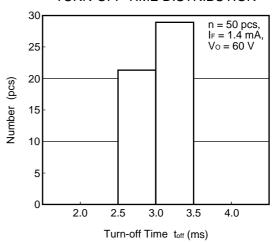
TURN-OFF TIME vs. FORWARD CURRENT



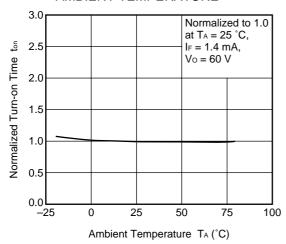
TURN-ON TIME DISTRIBUTION



TURN-OFF TIME DISTRIBUTION

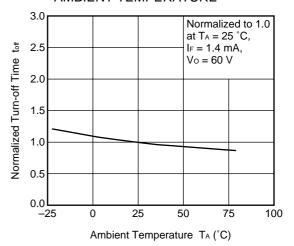


NORMALIZED TURN-ON TIME vs. AMBIENT TEMPERATURE

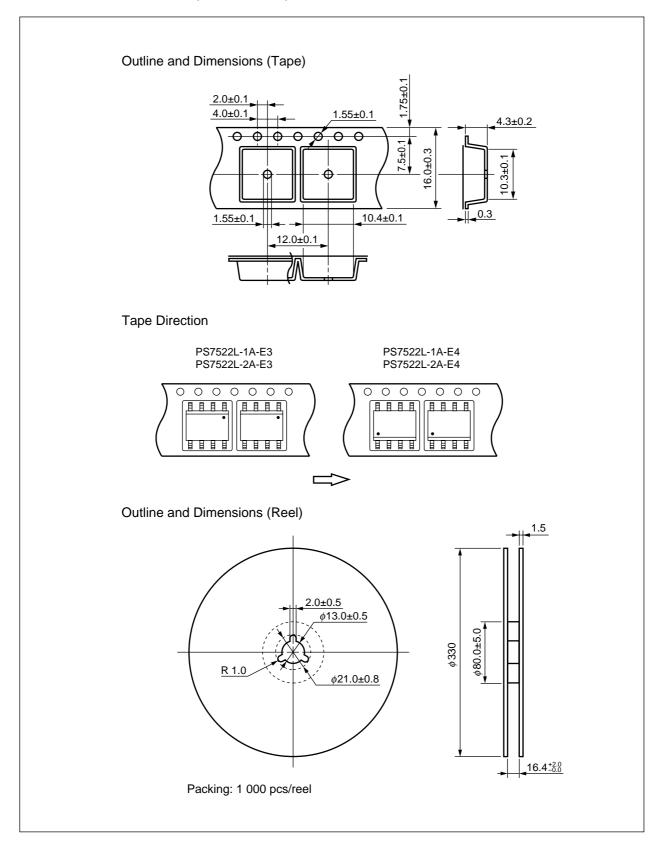


Remark The graphs indicate nominal characteristics.

NORMALIZED TURN-OFF TIME vs. AMBIENT TEMPERATURE



★ TAPING SPECIFICATIONS (in millimeters)



RECOMMENDED SOLDERING CONDITIONS

(1) Infrared reflow soldering

• Peak reflow temperature 235 °C (package surface temperature)

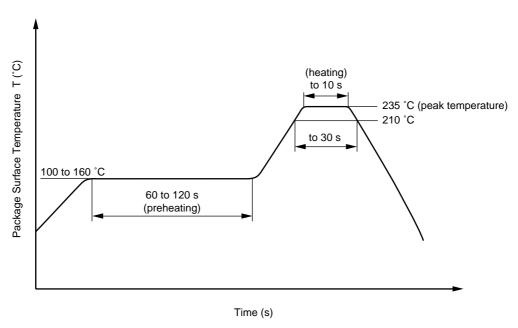
• Time of temperature higher than 210 °C 30 seconds or less

• Number of reflows Two

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt % is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Dip soldering

• Temperature 260 °C or below (molten solder temperature)

• Time 10 seconds or less

• Number of times One

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of

0.2 Wt % is recommended.)

(3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

[MEMO]

CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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